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May 2012

# **FDMA7628**

# Single N-Channel 1.5 V Specified PowerTrench® MOSFET **20 V, 9.4 A, 14.5 m**Ω

### **Features**

- Max  $r_{DS(on)}$  = 14.5 m $\Omega$  at  $V_{GS}$  = 4.5 V,  $I_D$  = 9.4 A
- Max  $r_{DS(on)}$  = 18.2 m $\Omega$  at  $V_{GS}$  = 2.5 V,  $I_D$  = 8.3 A
- Max  $r_{DS(on)} = 23.3 \text{ m}\Omega$  at  $V_{GS} = 1.8 \text{ V}$ ,  $I_D = 7.3 \text{ A}$
- Max  $r_{DS(on)} = 32.3 \text{ m}\Omega$  at  $V_{GS} = 1.5 \text{ V}$ ,  $I_D = 6.2 \text{ A}$
- Low Profile-0.8 mm maximum in the new package MicroFET
- RoHS Compliant

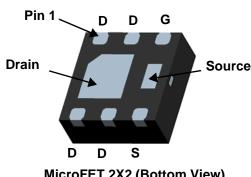
# **General Description**

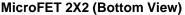
This Single N-Channel MOSFET has been designed using Fairchild Semiconductor's advanced Power Trench® process to optimize the  $r_{DS(ON)}$  @  $V_{GS}$  = 1.5 V on special MicroFET

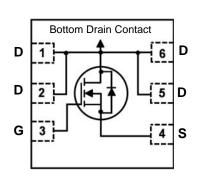
## **Applications**

- Li-Ion Battery Pack
- DC-DC Buck Converters









## MOSFET Maximum Ratings T<sub>A</sub> = 25 °C unless otherwise noted

Symbol	Parameter			Ratings	Units
$V_{DS}$	Drain to Source Voltage			20	V
$V_{GS}$	Gate to Source Voltage			±8	V
	-Continuous	T <sub>A</sub> = 25 °C	(Note 1a)	9.4	۸
'D	-Pulsed			54	A
D	Power Dissipation	T <sub>A</sub> = 25 °C	(Note 1a)	1.9	W
$P_{D}$	Power Dissipation	T <sub>A</sub> = 25 °C	(Note 1b)	0.7	VV
$T_J$ , $T_{STG}$	Operating and Storage Junction Temper	rature Range		-55 to +150	°C

#### Thermal Characteristics

$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	65	°C/M
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1b)	180	°C/W

#### Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
104	FDMA7628	MicroFET 2X2	7 "	12 mm	3000 units

# **Electrical Characteristics** $T_J = 25$ °C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	cteristics					
$BV_{DSS}$	Drain to Source Breakdown Voltage	$I_D = 250 \mu A, V_{GS} = 0 V$	20			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D$ = 250 $\mu$ A, referenced to 25 °C		15		mV/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 16 V, V <sub>GS</sub> = 0 V			1	μΑ
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS} = \pm 8 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA

### **On Characteristics**

V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu A$	0.4	0.6	1.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D$ = 250 $\mu$ A, referenced to 25 °C		-3		mV/°C
r Stati		$V_{GS} = 4.5 \text{ V}, I_D = 9.4 \text{ A}$		11.3	14.5	
		$V_{GS} = 2.5 \text{ V}, I_D = 8.3 \text{ A}$		12.7 18.3	18.2	- mΩ
	Static Drain to Source On Resistance	$V_{GS} = 1.8 \text{ V}, I_D = 7.3 \text{ A}$		15.0	23.3	
r <sub>DS(on)</sub>	Static Brain to Godice On Resistance	$V_{GS} = 1.5 \text{ V}, I_D = 6.2 \text{ A}$		18.3	32.3	
		$V_{GS} = 4.5 \text{ V}, I_D = 9.4 \text{ A},$ $T_J = 125 \text{ °C}$		14.7	18.3	
9 <sub>FS</sub>	Forward Transconductance	$V_{DD} = 5 \text{ V}, I_{D} = 9.4 \text{ A}$		56		S

## **Dynamic Characteristics**

C <sub>iss</sub>	Input Capacitance	V 40.V/.V/ 0.V/	1260	1680	pF
Coss	Output Capacitance	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V},$ f = 1  MHz	180	240	рF
C <sub>rss</sub>	Reverse Transfer Capacitance	1 - 1 101112	122	185	pF
$R_g$	Gate Resistance		1.9		Ω

## **Switching Characteristics**

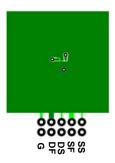
t <sub>d(on)</sub>	Turn-On Delay Time		9	17	ns
t <sub>r</sub>	Rise Time	V <sub>DD</sub> = 10 V, I <sub>D</sub> = 9.4 A,	6	11	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	$V_{GS}$ = 4.5 V, $R_{GEN}$ = 6 $\Omega$	37	58	ns
t <sub>f</sub>	Fall Time		6	11	ns
	Total Gate Charge	V <sub>GS</sub> = 0 V to 4.5 V	17.5		nC
0	Total Gate Charge	V <sub>GS</sub> = 0 V to 2.5 V	10.0		nC
$Q_g$	Total Gate Charge	$V_{GS} = 0 \text{ V to } 1.8 \text{ V} V_{DD} = 10 \text{ V},$	7.4		nC
	Total Gate Charge	V <sub>GS</sub> = 0 V to 1.5 V I <sub>D</sub> = 9.4 A	6.2		nC
Q <sub>gs</sub>	Gate to Source Charge		1.7		nC
$Q_{gd}$	Gate to Drain "Miller" Charge		2.7		nC

## **Drain-Source Diode Characteristics**

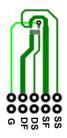
I <sub>S</sub>	Maximum Continuous Drain-Source Diode Forward Current				2.0	Α
$V_{SD}$	Source to Drain Diode Forward Voltage	$V_{GS} = 0 \text{ V}, I_{S} = 2.0 \text{ A}$ (Note 2)		0.63	1.2	V
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 9.4 A, di/dt = 100 A/μs		16	29	ns
Q <sub>rr</sub>	Reverse Recovery Charge			5	10	nC

#### NOTES:

 $R_{\theta JA}$  is determined with the device mounted on a 1 in 2 pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material.  $R_{\theta JC}$  is guaranteed by design while  $R_{\theta JA}$  is determined by the user's board design.



a.65 °C/W when mounted on a 1 in<sup>2</sup> pad of 2 oz copper.



b. 180 °C/W when mounted on a minimum pad of 2 oz copper.

2. Pulse Test: Pulse Width < 300  $\mu$ s, Duty cycle < 2.0%.

## **Typical Characteristics** $T_J = 25$ °C unless otherwise noted

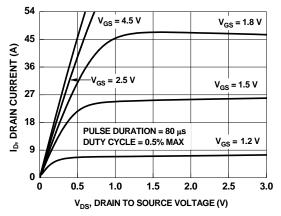


Figure 1. On Region Characteristics

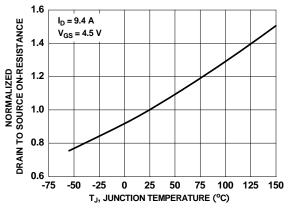


Figure 3. Normalized On Resistance vs Junction Temperature

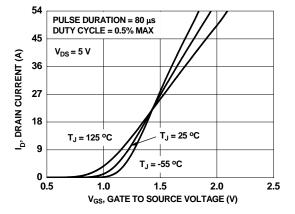


Figure 5. Transfer Characteristics

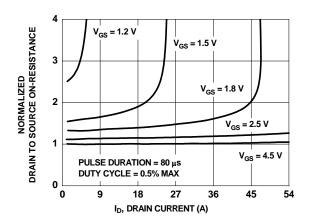


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

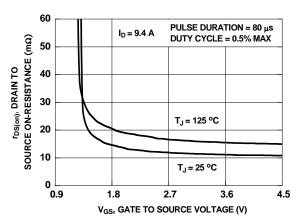


Figure 4. On-Resistance vs Gate to Source Voltage

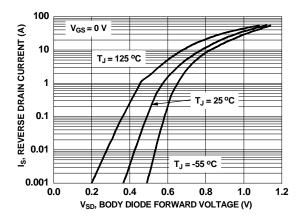


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

# **Typical Characteristics** $T_J = 25$ °C unless otherwise noted

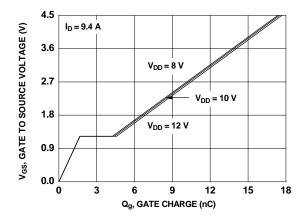


Figure 7. Gate Charge Characteristics

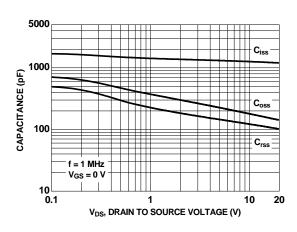


Figure 8. Capacitance vs Drain to Source Voltage

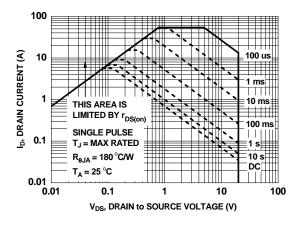


Figure 9. Forward Bias Safe Operating Area

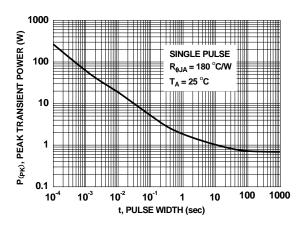


Figure 10. Single Pulse Maximum Power Dissipation

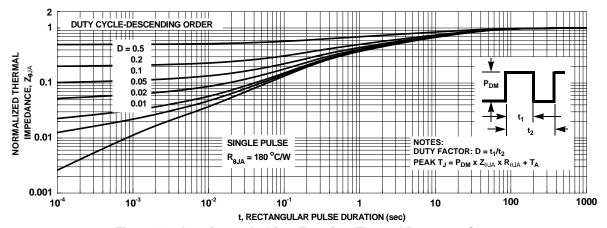
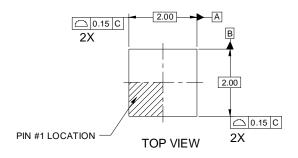
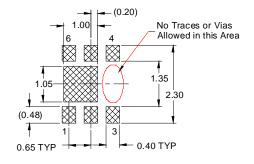


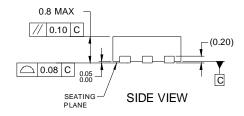
Figure 11. Junction-to-Ambient Transient Thermal Response Curve

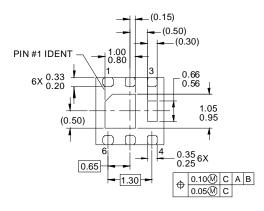
## **Dimensional Outline and Pad Layout**

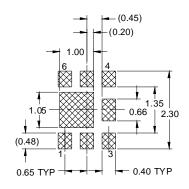




**RECOMMENDED LAND PATTERN OPT 1** 







**BOTTOM VIEW** 

**RECOMMENDED LAND PATTERN OPT 2** 

#### NOTES:

- A. DOES NOT FULLY CONFORM TO JEDEC REGISTRATION MO-229 DATED AUG/2003
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994





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